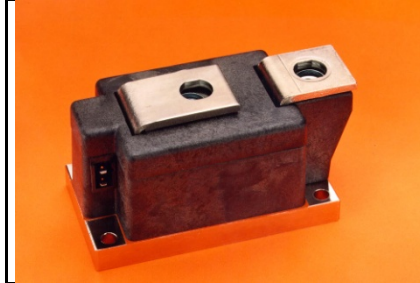
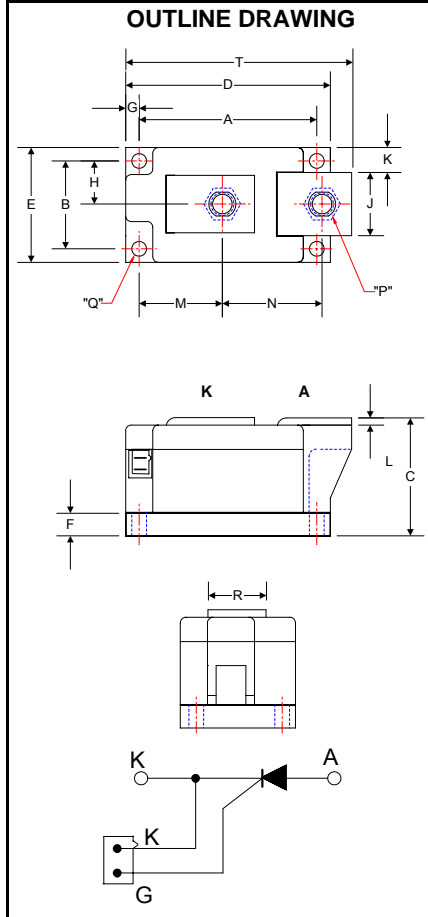


Powerex, Inc., 173 Pavilion Lane, Youngwood, Pennsylvania 15697 (724) 925-7272
www.pwr.com

POW-R-BLOK™
Single SCR Isolated Module
500 Amperes / Up to 1600 Volts



LS43__50
Single SCR
POW-R-BLOK™ Module
500 Amperes / Up to 1600 Volts

LS43 Outline Dimensions

Dimension	Inches	Millimeters
A	3.15	80.0
B	1.50	38.0
C	2.05	52.1
D	3.62	92.0
E	1.97	50.0
F	0.39	9.9
G	0.24	6.1
H	0.75	19.0
J	0.99	25.1
K	0.48	12.2
L	0.12	3.1
M	1.45	36.8
N	1.76	44.7
P	M10 Metric	M10
Q	0.250 Dia.	6.35 Dia.
R	0.99	25.1
S	0.110 x .032	2.5 x 0.8

Note: Dimensions are for reference only.

Ordering Information:

Select the complete eight-digit module part number from the table below.

Example: LS431650 is a 1600 Volt, 500 Ampere Single SCR Isolated POW-R-BLOK™ Module

Type	Voltage Volts (x100)	Current Amperes (x10)
LS43	08	50
	10	
	12	
	14	
	16	

Description:

Powerex Single SCR Modules are designed for use in applications requiring rectification and isolated packaging. The modules are isolated for easy mounting with other components on a common heatsink. POW-R-BLOK™ has been tested and recognized by the Underwriters Laboratories.

Features:

- Electrically Isolated Heatsinking
- Aluminum Nitride Insulator
- Compression Bonded Elements
- Metal Baseplate
- Low Thermal Impedance for Improved Current Capability
- Quick Connect Gate Terminal with Provision for Keyed Mating Plug
- UL Recognized

Benefits:

- No Additional Insulation Components Required
- Easy Installation
- No Clamping Components Required
- Reduce Engineering Time

Applications:

- Bridge Circuits
- AC & DC Motor Drives
- Battery Supplies
- Power Supplies
- Large IGBT Circuit Front Ends

Absolute Maximum Ratings

Characteristics	Conditions	Symbol		Units
Repetitive Peak Forward and Reverse Blocking Voltage		V_{DRM} & V_{RRM}	up to 1600	V
Non-Repetitive Peak Blocking Voltage ($t < 5$ msec)		V_{RSM}	$V_{RRM} + 100$	V
RMS Forward Current	180° Conduction, $T_C=78^\circ\text{C}$	$I_{T(RMS)}$	900	A
Average Forward Current	180° Conduction, $T_C=86^\circ\text{C}$	$I_{T(AV)}$	500	A
	180° Conduction, $T_C=78^\circ\text{C}$	$I_{T(AV)}$	575	A
Peak One Cycle Surge Current, Non-Repetitive	60 Hz, 100% V_{RRM} reapplied	I_{TSM}	17,000	A
	50 Hz, 100% V_{RRM} reapplied	I_{TSM}	16,300	A
Peak Three Cycle Surge Current, Non-Repetitive	60 Hz, 100% V_{RRM} reapplied	I_{TSM}	12,250	A
Peak Ten Cycle Surge Current, Non-Repetitive	60 Hz, 100% V_{RRM} reapplied	I_{TSM}	10,500	A
I^2t for Fusing for One Cycle	8.3 milliseconds	I^2t	1.20×10^6	$\text{A}^2 \text{sec}$
	10 milliseconds	I^2t	1.33×10^6	$\text{A}^2 \text{sec}$
Maximum Rate-of-Rise of On-State Current, (Repetitive)	Per JEDEC Standard 397 5.2.2.6	di/dt	200	$\text{A}/\mu\text{s}$
Operating Temperature		T_J	-40 to +130	$^\circ\text{C}$
Storage Temperature		T_{stg}	-40 to +150	$^\circ\text{C}$
Max. Mounting Torque, M6 Mounting Screw			55	in. – Lb.
			6	Nm
Max. Mounting Torque, M10 Terminal Screw			110	in. – Lb.
			12	Nm
Module Weight, Typical			816	g
			1.80	lb
V Isolation @ 25C		V_{rms}	3000	V

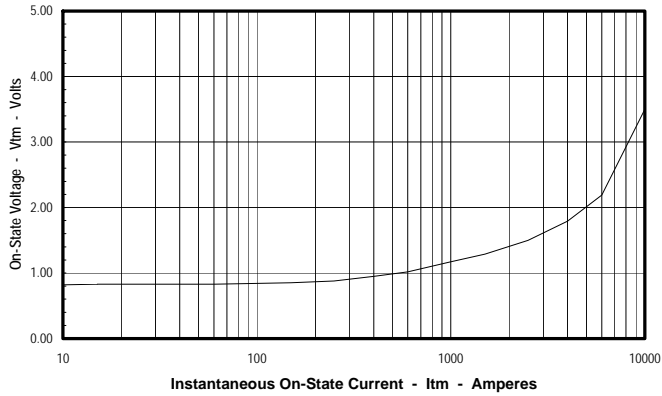
Electrical Characteristics, $T_J=25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Max.	Units
Repetitive Peak Forward Leakage Current	I_{DRM}	Up to 1600V, $T_J=130^\circ\text{C}$		80	mA
Repetitive Peak Reverse Leakage Current	I_{RRM}	Up to 1600V, $T_J=130^\circ\text{C}$		80	mA
Peak On-State Voltage	V_{FM}	$I_{TM}=1500\text{A}$		1.30	V
Threshold Voltage, Low-level	$V_{(TO)1}$	$T_J = 130^\circ\text{C}$, $I = 15\%I_{T(AV)}$ to $\pi I_{T(AV)}$		0.81	V
Slope Resistance, Low-level	r_{T1}			0.32	$\text{m}\Omega$
Threshold Voltage, High-level	$V_{(TO)2}$	$T_J = 130^\circ\text{C}$, $I = \pi I_{T(AV)}$ to I_{TSM}		0.90	V
Slope Resistance, High-level	r_{T2}			0.26	$\text{m}\Omega$
V_{TM} Coefficients, Full Range		$T_J = 130^\circ\text{C}$, $I = 10\text{A}$ to 6kA	A =	0.8824	
			B =	-4.46E-02	
		$V_{TM} = A + B \ln I + C I + D \text{Sqrt } I$	C =	8.12E-05	
			D =	1.54E-02	
Minimum dV/dt	dV/dt	Exponential to V_{DRM} $T_J=130^\circ\text{C}$, Gate Open	1000 Typ.		V/ μs
Gate Trigger Current	I_{GT}	$T_J=25^\circ\text{C}$, $V_D=12\text{V}$		200	mA
Gate Trigger Voltage	V_{GT}	$T_J=25^\circ\text{C}$, $V_D=12\text{V}$		3.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_J=130^\circ\text{C}$, $V_D= \frac{1}{2} V_{DRM}$		0.25	Volts
Peak Forward Gate Current	I_{GTM}			4.0	Amp
Peak Reverse Gate Voltage	V_{GRM}			5	Volts

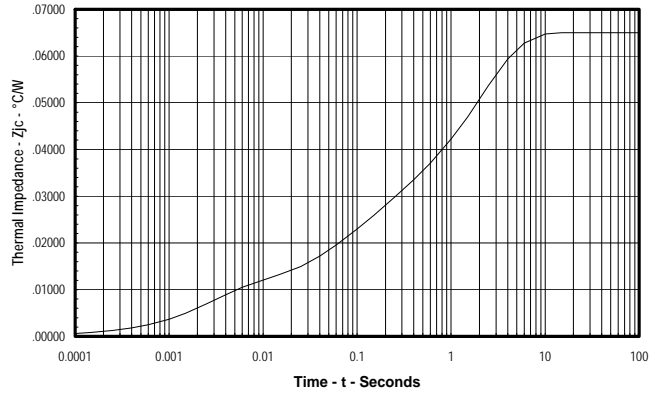
Thermal Characteristics

Characteristics	Symbol		Max.	Units
Thermal Resistance, Junction to Case	$R_{\theta J-C}$	Per Module/Junction	0.0650	$^\circ\text{C}/\text{W}$
Thermal Impedance Coefficients	$Z_{\theta J-C}$	$Z_{\theta J-C} = K_1 (1 - \exp(-t/\tau_1))$ $+ K_2 (1 - \exp(-t/\tau_2))$ $+ K_3 (1 - \exp(-t/\tau_3))$ $+ K_4 (1 - \exp(-t/\tau_4))$	$K_1 = 8.03\text{E-}04$ $K_2 = 1.03\text{E-}02$ $K_3 = 1.64\text{E-}02$ $K_4 = 3.75\text{E-}02$	$\tau_1 = 3.39\text{E-}04$ $\tau_2 = 3.15\text{E-}03$ $\tau_3 = 0.106$ $\tau_4 = 2.066$
Thermal Resistance, Case to Sink Lubricated	$R_{\theta C-S}$	Per Module	0.02	$^\circ\text{C}/\text{W}$

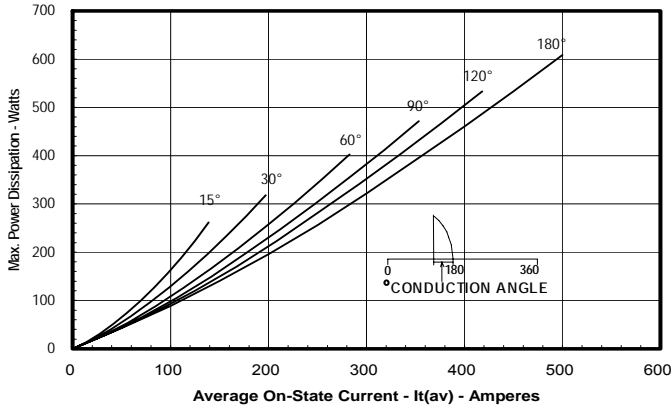
Maximum On-State Forward Voltage Drop
($T_j = 130^\circ\text{C}$)



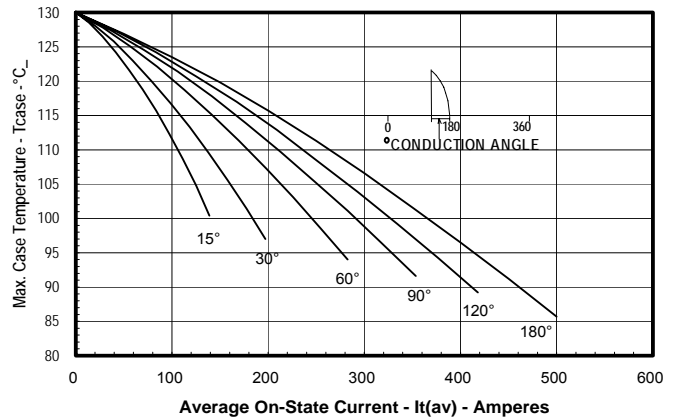
Maximum Transient Thermal Impedance
(Junction to Case)



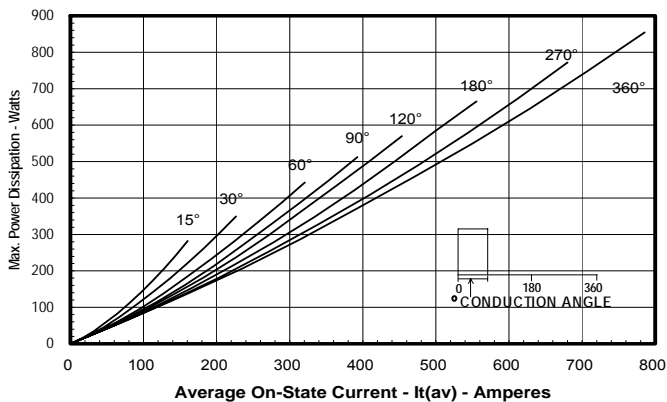
Maximum On-State Power Dissipation
(Sinusoidal Waveform)



Maximum Allowable Case Temperature
(Sinusoidal Waveform)



Maximum On-State Power Dissipation
(Rectangular Waveform)



Maximum Allowable Case Temperature
(Rectangular Waveform)

